



256K X 36, 512K X 18
2.5V Synchronous SRAMs
2.5V I/O, Burst Counter
Flow-Through Outputs, Single Cycle Deselect

Advance
Information
IDT71T67702
IDT71T67902

Features

- ◆ 256K x 36, 512K x 18 memory configurations
- ◆ Supports fast access times:
 - 7.5ns up to 117MHz clock frequency
 - 8.0ns up to 100MHz clock frequency
 - 8.5ns up to 87MHz clock frequency
- ◆ $\overline{\text{LBO}}$ input selects interleaved or linear burst mode
- ◆ Self-timed write cycle with global write control ($\overline{\text{GW}}$), byte write enable ($\overline{\text{BWE}}$), and byte writes ($\overline{\text{BWx}}$)
- ◆ 2.5V core power supply
- ◆ Power down controlled by ZZ input
- ◆ 2.5V I/O supply (VDDO)
- ◆ Packaged in a JEDEC Standard 100-pin plastic thin quad flatpack (TQFP), 119 ball grid array (BGA) and 165 fine pitch ball grid array (fBGA)

Description

The IDT71T67702/7902 are high-speed SRAMs organized as 256K x 36/512K x 18. The IDT71T67702/7902 SRAMs contain write,

data, address and control registers. There are no registers in the data output path (flow-through architecture). Internal logic allows the SRAM to generate a self-timed write based upon a decision which can be left until the end of the write cycle.

The burst mode feature offers the highest level of performance to the system designer, as the IDT71T67702/7902 can provide four cycles of data for a single address presented to the SRAM. An internal burst address counter accepts the first cycle address from the processor, initiating the access sequence. The first cycle of output data will flow-through from the array after a clock-to-data access time delay from the rising clock edge of the same cycle. If burst mode operation is selected ($\text{ADV}=\text{LOW}$), the subsequent three cycles of output data will be available to the user on the next three rising clock edges. The order of these three addresses are defined by the internal burst counter and the $\overline{\text{LBO}}$ input pin.

The IDT71T67702/7902 SRAMs utilize IDT's latest high-performance CMOS process and are packaged in a JEDEC standard 14mm x 20mm 100-pin thin plastic quad flatpack (TQFP) as well as a 119 ball grid array (BGA) and a 165 fine pitch ball grid array (fBGA).

Pin Description Summary

| | | | |
|---|-----------------------------------|--------|--------------|
| A0-A18 | Address Inputs | Input | Synchronous |
| $\overline{\text{CE}}$ | Chip Enable | Input | Synchronous |
| CS ₀ , $\overline{\text{CS}}_1$ | Chip Selects | Input | Synchronous |
| $\overline{\text{OE}}$ | Output Enable | Input | Asynchronous |
| $\overline{\text{GW}}$ | Global Write Enable | Input | Synchronous |
| $\overline{\text{BWE}}$ | Byte Write Enable | Input | Synchronous |
| $\overline{\text{BW}}_1$, $\overline{\text{BW}}_2$, $\overline{\text{BW}}_3$, $\overline{\text{BW}}_4^{(1)}$ | Individual Byte Write Selects | Input | Synchronous |
| CLK | Clock | Input | N/A |
| $\overline{\text{ADV}}$ | Burst Address Advance | Input | Synchronous |
| $\overline{\text{ADSC}}$ | Address Status (Cache Controller) | Input | Synchronous |
| $\overline{\text{ADSP}}$ | Address Status (Processor) | Input | Synchronous |
| $\overline{\text{LBO}}$ | Linear / Interleaved Burst Order | Input | DC |
| ZZ | Sleep Mode | Input | Asynchronous |
| TMS | Test Mode Select | Input | N/A |
| TDI | Test Data Input | Input | N/A |
| TCK | Test Clock | Input | N/A |
| TDO | Test Data Output | Output | N/A |
| I/O ₀ -I/O ₃₁ , I/OP ₁ -I/OP ₄ | Data Input / Output | I/O | Synchronous |
| V _{DD} , V _{DDO} | Core Power, I/O Power | Supply | N/A |
| V _{SS} | Ground | Supply | N/A |

NOTE:

1. $\overline{\text{BW}}_3$ and $\overline{\text{BW}}_4$ are not applicable for the IDT71T67902.

5291 tbl 01

JULY 2001

Pin Definitions⁽¹⁾

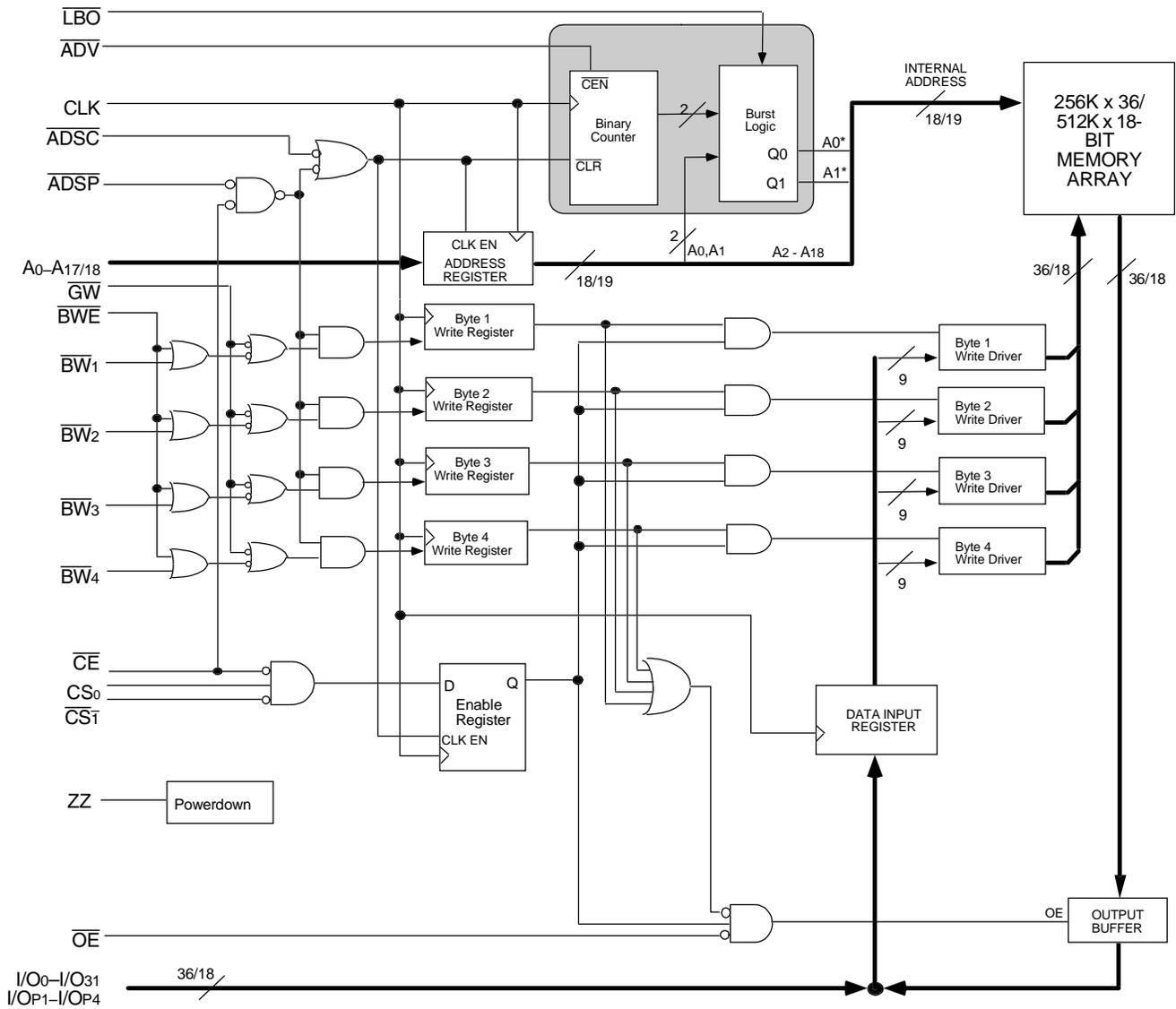
| Symbol | Pin Function | I/O | Active | Description |
|-------------------------------------|-----------------------------------|-----|--------|--|
| A0-A18 | Address Inputs | I | N/A | Synchronous Address inputs. The address register is triggered by a combination of the rising edge of CLK and \overline{ADSC} Low or \overline{ADSP} Low and \overline{CE} Low. |
| \overline{ADSC} | Address Status (Cache Controller) | I | LOW | Synchronous Address Status from Cache Controller. \overline{ADSC} is an active LOW input that is used to load the address registers with new addresses. |
| \overline{ADSP} | Address Status (Processor) | I | LOW | Synchronous Address Status from Processor. \overline{ADSP} is an active LOW input that is used to load the address registers with new addresses. \overline{ADSP} is gated by \overline{CE} . |
| \overline{ADV} | Burst Address Advance | I | LOW | Synchronous Address Advance. \overline{ADV} is an active LOW input that is used to advance the internal burst counter, controlling burst access after the initial address is loaded. When the input is HIGH the burst counter is not incremented; that is, there is no address advance. |
| \overline{BWE} | Byte Write Enable | I | LOW | Synchronous byte write enable gates the byte write inputs $\overline{BW1}$ - $\overline{BW4}$. If \overline{BWE} is LOW at the rising edge of CLK then \overline{BWx} inputs are passed to the next stage in the circuit. If \overline{BWE} is HIGH then the byte write inputs are blocked and only \overline{GW} can initiate a write cycle. |
| $\overline{BW1}$ - $\overline{BW4}$ | Individual Byte Write Enables | I | LOW | Synchronous byte write enables. $\overline{BW1}$ controls I/O0-7, I/OP1, $\overline{BW2}$ controls I/O8-15, I/OP2, etc. Any active byte write causes all outputs to be disabled. |
| \overline{CE} | Chip Enable | I | LOW | Synchronous chip enable. \overline{CE} is used with CS_0 and \overline{CS}_1 to enable the IDT71T67702/7902. \overline{CE} also gates \overline{ADSP} . |
| CLK | Clock | I | N/A | This is the clock input. All timing references for the device are made with respect to this input. |
| CS_0 | Chip Select 0 | I | HIGH | Synchronous active HIGH chip select. CS_0 is used with \overline{CE} and \overline{CS}_1 to enable the chip. |
| \overline{CS}_1 | Chip Select 1 | I | LOW | Synchronous active LOW chip select. \overline{CS}_1 is used with \overline{CE} and CS_0 to enable the chip. |
| \overline{GW} | Global Write Enable | I | LOW | Synchronous global write enable. This input will write all four 9-bit data bytes when LOW on the rising edge of CLK. \overline{GW} supersedes individual byte write enables. |
| I/O0-I/O31 I/OP1-I/OP4 | Data Input/Output | I/O | N/A | Synchronous data input/output (I/O) pins. The data input path is registered, triggered by the rising edge of CLK. The data output path is flow-through (no output register). |
| \overline{LBO} | Linear Burst Order | I | LOW | Asynchronous burst order selection input. When \overline{LBO} is HIGH, the inter-leaved burst sequence is selected. When \overline{LBO} is LOW the Linear burst sequence is selected. \overline{LBO} is a static input and must not change state while the device is operating. |
| \overline{OE} | Output Enable | I | LOW | Asynchronous output enable. When \overline{OE} is LOW the data output drivers are enabled on the I/O pins if the chip is also selected. When \overline{OE} is HIGH the I/O pins are in a high-impedance state. |
| TMS | Test Mode Select | I | N/A | Gives input command for TAP controller; sampled on rising edge of TCK. |
| TDI | Test Data Input | I | N/A | Serial input of registers placed between TDI and TDO. Sampled on rising edge of TCK. |
| TCK | Test Clock | I | N/A | Clock input of TAP controller. Each TAP event is clocked. Test inputs are captured on rising edge of TCK, while test outputs are driven from falling edge of TCK. |
| TDO | Test Data Output | O | N/A | Serial output of registers placed between TDI and TDO. This output is active depending on state fo TAP controller. |
| VDD | Power Supply | N/A | N/A | 2.5V core power supply. |
| VDDQ | Power Supply | N/A | N/A | 2.5V I/O Supply. |
| VSS | Ground | N/A | N/A | Ground. |
| NC | No Connect | N/A | N/A | NC pins are not electrically connected to the device. |
| ZZ | Sleep Mode | I | HIGH | Asynchronous sleep mode input. ZZ HIGH will gate the CLK internally and power down the IDT71T67702/7902 to its lowest power consumption level. Data retention is guaranteed in Sleep Mode. |

NOTE:

1. All synchronous inputs must meet specified setup and hold times with respect to CLK.

5291 tbl 02

Functional Block Diagram



5291 drw 01

Absolute Maximum Ratings⁽¹⁾

| Symbol | Rating | Commercial | Unit |
|------------------------------------|--------------------------------------|-------------------------------|------|
| V _{TERM} ⁽²⁾ | Terminal Voltage with Respect to GND | -0.5 to +3.6 | V |
| V _{TERM} ^(3,6) | Terminal Voltage with Respect to GND | -0.5 to V _{DD} | V |
| V _{TERM} ^(4,6) | Terminal Voltage with Respect to GND | -0.5 to V _{DD} +0.5 | V |
| V _{TERM} ^(5,6) | Terminal Voltage with Respect to GND | -0.5 to V _{DDQ} +0.5 | V |
| T _A ⁽⁷⁾ | Operating Temperature | -0 to +70 | °C |
| T _{BIAS} | Temperature Under Bias | -55 to +125 | °C |
| T _{STG} | Storage Temperature | -55 to +125 | °C |
| P _T | Power Dissipation | 2.0 | W |
| I _{OUT} | DC Output Current | 50 | mA |

5291 tbl 03

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{DD} terminals only.
- V_{DDQ} terminals only.
- Input terminals only.
- I/O terminals only.
- This is a steady-state DC parameter that applies after the power supplies have ramped up. Power supply sequencing is not necessary; however, the voltage on any input or I/O pin cannot exceed V_{DDQ} during power supply ramp up.
- T_A is the "instant on" case temperature.

Recommended Operating Temperature Supply Voltage

| Grade | Temperature ⁽¹⁾ | V _{SS} | V _{DD} | V _{DDQ} |
|------------|----------------------------|-----------------|-----------------|------------------|
| Commercial | 0°C to +70°C | 0V | 2.5V±5% | 2.5V±5% |

NOTE:

5291 tbl 04

- T_A is the "instant on" case temperature.

Recommended DC Operating Conditions

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|------------------|-----------------------------|---------------------|------|-----------------------|------|
| V _{DD} | Core Supply Voltage | 2.375 | 2.5 | 2.625 | V |
| V _{DDQ} | I/O Supply Voltage | 2.375 | 2.5 | 2.625 | V |
| V _{SS} | Ground | 0 | 0 | 0 | V |
| V _{IH} | Input High Voltage - Inputs | 1.7 | — | V _{DD} +0.3 | V |
| V _{IH} | Input High Voltage - I/O | 1.7 | — | V _{DDQ} +0.3 | V |
| V _{IL} | Input Low Voltage | -0.3 ⁽¹⁾ | — | 0.7 | V |

5291 tbl 05

NOTE:

- V_{IL} (min) = -0.8V for pulse width less than tcvc/2, once per cycle.

TQFP Capacitance (T_A = +25°C, f = 1.0MHz)

| Symbol | Parameter ⁽¹⁾ | Conditions | Max. | Unit |
|------------------|--------------------------|------------------------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 3dV | 5 | pF |
| C _{I/O} | I/O Capacitance | V _{OUT} = 3dV | 7 | pF |

5291 tbl 06

BGA Capacitance (T_A = +25°C, f = 1.0MHz)

| Symbol | Parameter ⁽¹⁾ | Conditions | Max. | Unit |
|------------------|--------------------------|------------------------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 3dV | 7 | pF |
| C _{I/O} | I/O Capacitance | V _{OUT} = 3dV | 7 | pF |

5291 tbl 06a

fBGA Capacitance (T_A = +25°C, f = 1.0MHz)

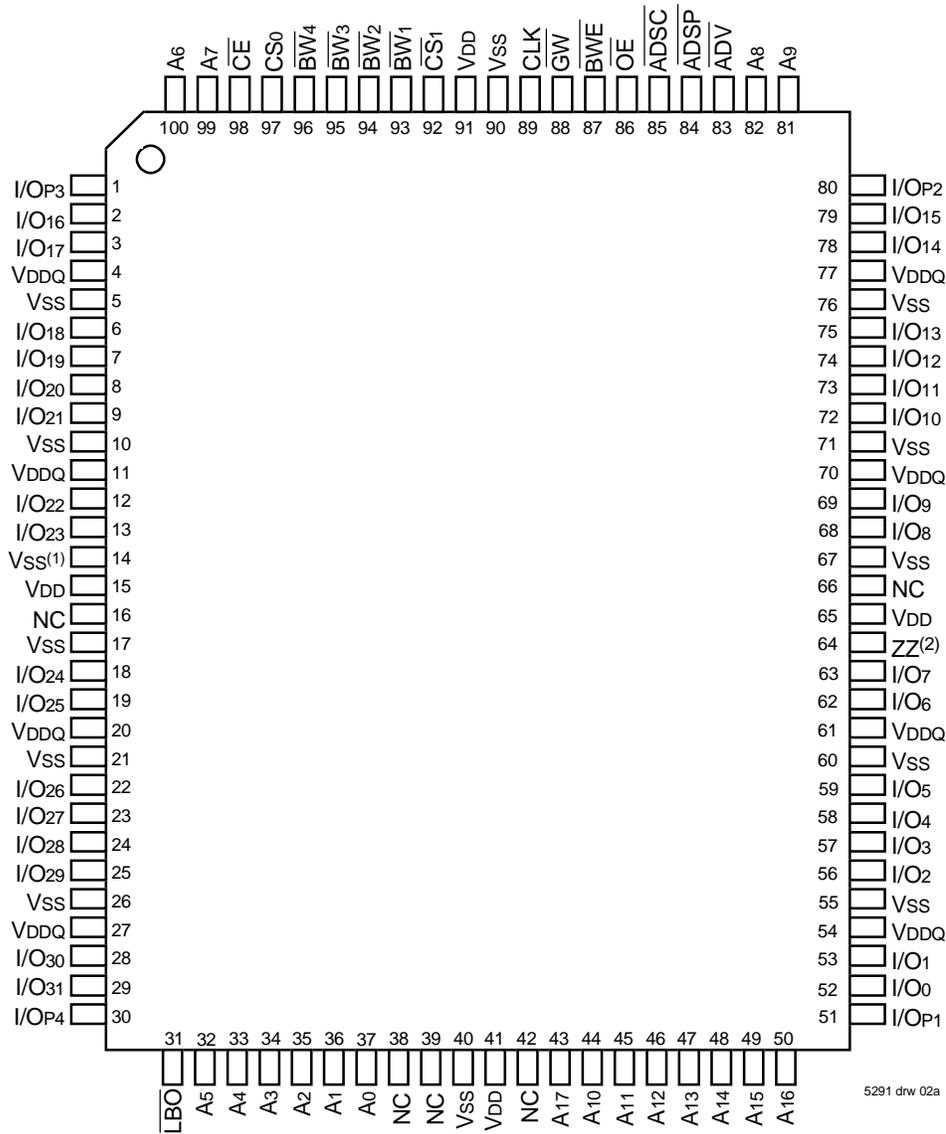
| Symbol | Parameter ⁽¹⁾ | Conditions | Max. | Unit |
|------------------|--------------------------|------------------------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 3dV | TBD | pF |
| C _{I/O} | I/O Capacitance | V _{OUT} = 3dV | TBD | pF |

5291 tbl 06b

NOTE:

- This parameter is guaranteed by device characterization, but not production tested.

Pin Configuration – 256K x 36, 100-pin TQFP

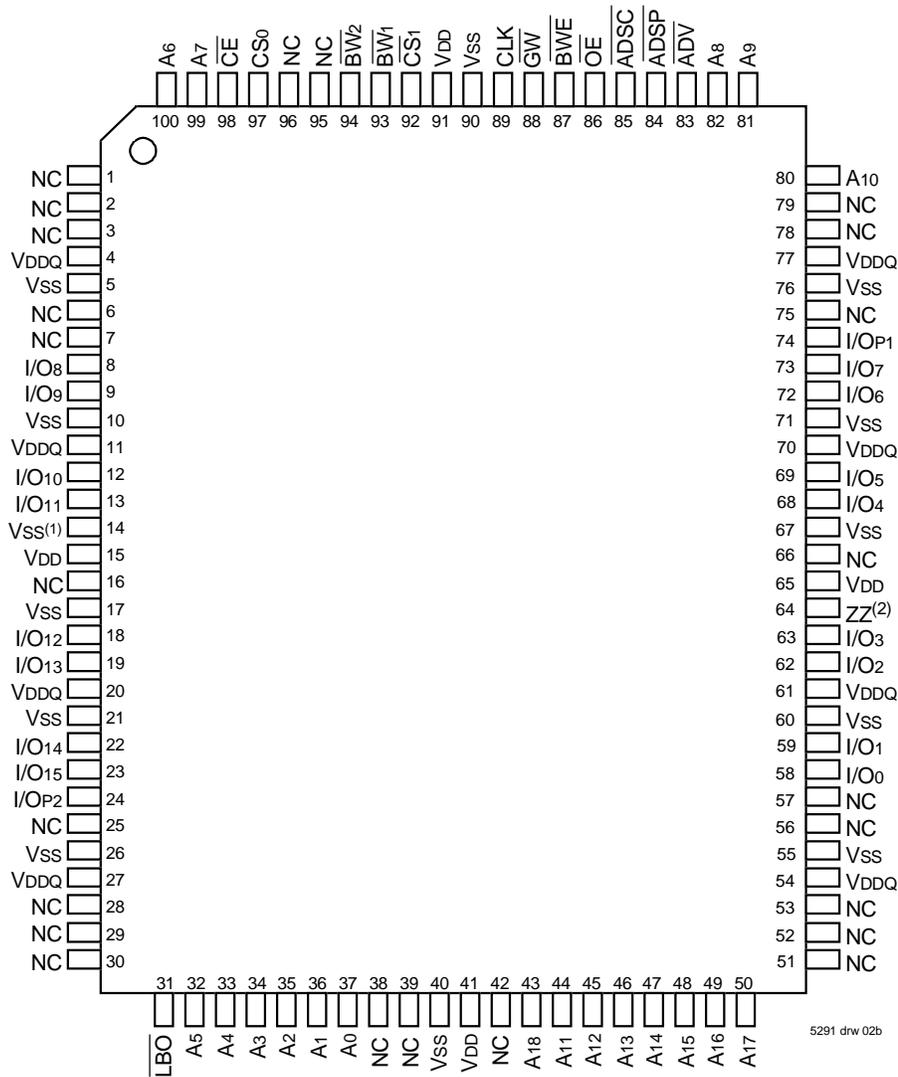


Top View

NOTES:

1. Pin 14 does not have to be directly connected to Vss as long as the input voltage is $\leq V_{IL}$.
2. Pin 64 can be left unconnected and the device will always remain in active mode.

Pin Configuration – 512K x 18, 100-pin TQFP

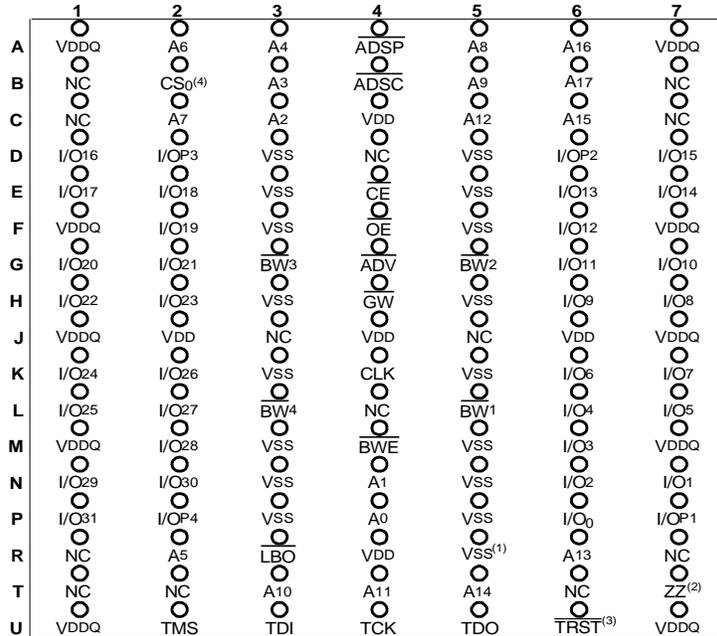


Top View

NOTES:

1. Pin 14 does not have to be directly connected to Vss as long as the input voltage is $\leq V_{IL}$.
2. Pin 64 can be left unconnected and the device will always remain in active mode.

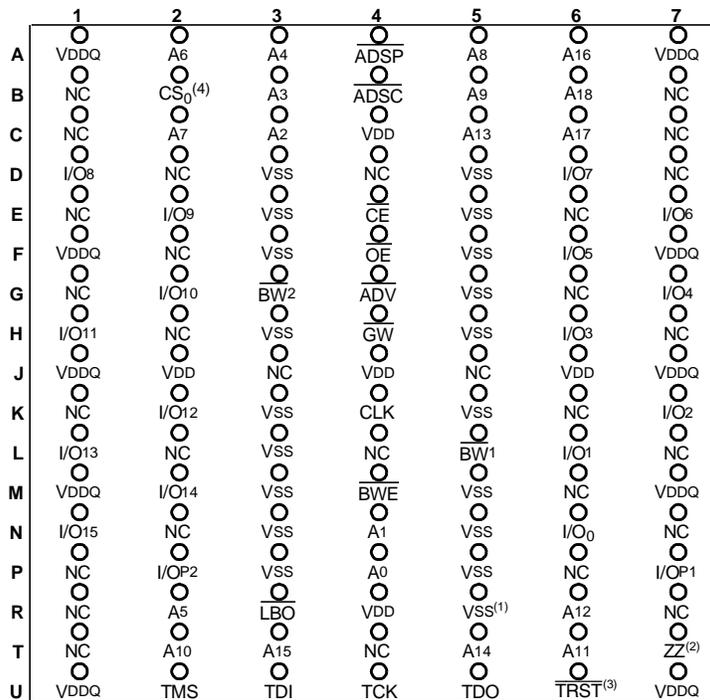
Pin Configuration – 256K x 36, 119 BGA



5291 drw 02c

Top View

Pin Configuration – 512K x 18, 119 BGA



5291 drw 02d

Top View

NOTES:

1. R5 does not have to be directly connected to Vss as long as the input voltage is $\leq V_{IL}$.
2. T7 can be left unconnected and the device will always remain in active mode.
3. Pin U6 will be internally pulled to VDD if not actively driven. To disable the TAP controller without interfering with normal operation, TRST should be tied low and TCK, TDI, and TMS should be pulled through a resistor to 3.3V. TDO should be left unconnected.
4. On future 18M device CS₀ will be removed, B2 will be used for address expansion.

Pin Configuration – 256K x 36, 165 fBGA

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|--------------------|-------------------|-----------------|-------------------|-------------------|-------------------|------------------|-------------------|-------------------|-------|-------------------|
| A | NC ⁽³⁾ | A7 | \overline{CE} | \overline{BW}_3 | \overline{BW}_2 | \overline{CS}_1 | \overline{BWE} | \overline{ADSC} | \overline{ADV} | A8 | NC |
| B | NC | A6 | CS0 | \overline{BW}_4 | \overline{BW}_1 | CLK | \overline{GW} | \overline{OE} | \overline{ADSP} | A9 | NC ⁽³⁾ |
| C | I/OP3 | NC | VDDQ | VSS | VSS | VSS | VSS | VSS | VDDQ | NC | I/OP2 |
| D | I/O17 | I/O16 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O15 | I/O14 |
| E | I/O19 | I/O18 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O13 | I/O12 |
| F | I/O21 | I/O20 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O11 | I/O10 |
| G | I/O23 | I/O22 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O9 | I/O8 |
| H | VSS ⁽¹⁾ | NC | NC | VDD | VSS | VSS | VSS | VDD | NC | NC | ZZ ⁽²⁾ |
| J | I/O25 | I/O24 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O7 | I/O6 |
| K | I/O27 | I/O26 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O5 | I/O4 |
| L | I/O29 | I/O28 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O3 | I/O2 |
| M | I/O31 | I/O30 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O1 | I/O0 |
| N | I/OP4 | NC | VDDQ | VSS | NC | NC ⁽³⁾ | NC | VSS | VDDQ | NC | I/OP1 |
| P | NC | NC ⁽³⁾ | A5 | A2 | TDI | A1 | TDO | A10 | A13 | A14 | A17 |
| R | \overline{LBO} | NC ⁽³⁾ | A4 | A3 | TMS | A0 | TCK | A11 | A12 | A15 | A16 |

5291 tbl 17a

Pin Configuration – 512K x 18, 165 fBGA

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|--------------------|-------------------|-----------------|-------------------|-------------------|-------------------|------------------|-------------------|-------------------|------|-------------------|
| A | NC ⁽³⁾ | A7 | \overline{CE} | \overline{BW}_2 | NC | \overline{CS}_1 | \overline{BWE} | \overline{ADSC} | \overline{ADV} | A8 | A10 |
| B | NC | A6 | CS0 | NC | \overline{BW}_1 | CLK | \overline{GW} | \overline{OE} | \overline{ADSP} | A9 | NC ⁽³⁾ |
| C | NC | NC | VDDQ | VSS | VSS | VSS | VSS | VSS | VDDQ | NC | I/OP1 |
| D | NC | I/O8 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | NC | I/O7 |
| E | NC | I/O9 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | NC | I/O6 |
| F | NC | I/O10 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | NC | I/O5 |
| G | NC | I/O11 | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | NC | I/O4 |
| H | VSS ⁽¹⁾ | NC | NC | VDD | VSS | VSS | VSS | VDD | NC | NC | ZZ ⁽²⁾ |
| J | I/O12 | NC | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O3 | NC |
| K | I/O13 | NC | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O2 | NC |
| L | I/O14 | NC | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O1 | NC |
| M | I/O15 | NC | VDDQ | VDD | VSS | VSS | VSS | VDD | VDDQ | I/O0 | NC |
| N | I/OP2 | NC | VDDQ | VSS | NC | NC ⁽³⁾ | NC | VSS | VDDQ | NC | NC |
| P | NC | NC ⁽³⁾ | A5 | A2 | TDI | A1 | TDO | A11 | A14 | A15 | A18 |
| R | \overline{LBO} | NC ⁽³⁾ | A4 | A3 | TMS | A0 | TCK | A12 | A13 | A16 | A17 |

5291 tbl 17b

NOTES:

1. H1 does not have to be directly connected to Vss as long as the input voltage is $\leq V_{IL}$.
2. H11 can be left unconnected and the device will always remain in active mode.
3. Pin N6, B11, A1, R2 and P2 are reserved for 18M, 36M, 72M, and 144M and 288M respectively.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range ($V_{DD} = 2.5V \pm 5\%$)

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit |
|------------|---|--|------|------|---------|
| $ I_{L} $ | Input Leakage Current | $V_{DD} = \text{Max.}, V_{IN} = 0V \text{ to } V_{DD}$ | — | 5 | μA |
| $ I_{L} $ | $\overline{LB0}$ Input Leakage Current ⁽¹⁾ | $V_{DD} = \text{Max.}, V_{IN} = 0V \text{ to } V_{DD}$ | — | 30 | μA |
| $ I_{LO} $ | Output Leakage Current | $V_{OUT} = 0V \text{ to } V_{CC}$ | — | 5 | μA |
| V_{OL} | Output Low Voltage | $I_{OL} = +6mA, V_{DD} = \text{Min.}$ | — | 0.4 | V |
| V_{OH} | Output High Voltage | $I_{OH} = -6mA, V_{DD} = \text{Min.}$ | 2.0 | — | V |

5291 tbl 07

NOTE:

- The $\overline{LB0}$ pin will be internally pulled to V_{DD} if it is not actively driven in the application and the ZZ in will be internally pulled to V_{SS} if not actively driven.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range ⁽¹⁾

| Symbol | Parameter | Test Conditions | 7.5ns | 8ns | 8.5ns | Unit |
|-----------|------------------------------------|---|-------|-----|-------|------|
| I_{DD} | Operating Power Supply Current | Device Selected, Outputs Open, $V_{DD} = \text{Max.}, V_{DDQ} = \text{Max.}, V_{IN} \geq V_{IH} \text{ or } \leq V_{IL}, f = f_{MAX}^{(2)}$ | 255 | 200 | 180 | mA |
| I_{SB1} | CMOS Standby Power Supply Current | Device Deselected, Outputs Open, $V_{DD} = \text{Max.}, V_{DDQ} = \text{Max.}, V_{IN} \geq V_{HD} \text{ or } \leq V_{LD}, f = 0^{(2,3)}$ | 40 | 40 | 40 | mA |
| I_{SB2} | Clock Running Power Supply Current | Device Deselected, Outputs Open, $V_{DD} = \text{Max.}, V_{DDQ} = \text{Max.}, V_{IN} \geq V_{HD} \text{ or } \leq V_{LD}, f = f_{MAX}^{(2,3)}$ | 135 | 130 | 125 | mA |
| I_{ZZ} | Full Sleep Mode Supply Current | $ZZ \geq V_{HD}, V_{DD} = \text{Max.}$ | 40 | 40 | 40 | mA |

5291 tbl 08

NOTES:

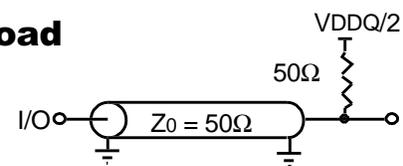
- All values are maximum guaranteed values.
- At $f = f_{MAX}$, inputs are cycling at the maximum frequency of read cycles of $1/t_{CYC}$ while $\overline{ADSC} = \text{LOW}$; $f=0$ means no input lines are changing.
- For I/Os $V_{HD} = V_{DDQ} - 0.2V, V_{LD} = 0.2V$. For other inputs $V_{HD} = V_{DD} - 0.2V, V_{LD} = 0.2V$.

AC Test Conditions ($V_{DDQ} = 3.3V/2.5V$)

| | |
|--------------------------------|--------------|
| Input Pulse Levels | 0 to 2.5V |
| Input Rise/Fall Times | 2ns |
| Input Timing Reference Levels | $V_{DDQ}/2$ |
| Output Timing Reference Levels | $V_{DDQ}/2$ |
| AC Test Load | See Figure 1 |

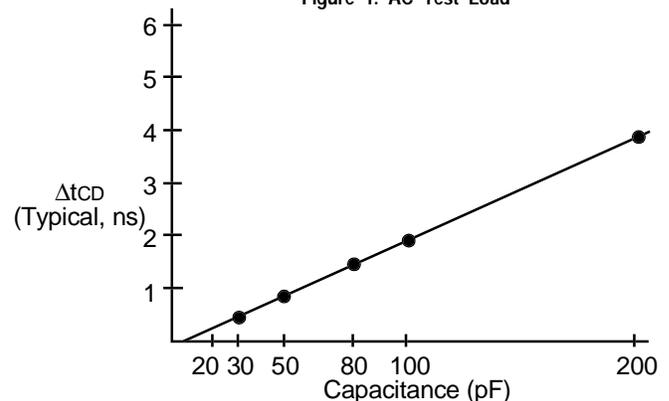
5291 tbl 09

AC Test Load



5291 drw 03

Figure 1. AC Test Load



5291 drw 05

Figure 2. Lumped Capacitive Load, Typical Derating

Synchronous Truth Table (1,3)

| Operation | Address Used | \overline{CE} | CS ₀ | \overline{CS}_1 | \overline{ADSP} | \overline{ADSC} | \overline{ADV} | \overline{GW} | \overline{BWE} | \overline{BW}_x | $\overline{OE}^{(2)}$ | CLK | I/O |
|------------------------------|--------------|-----------------|-----------------|-------------------|-------------------|-------------------|------------------|-----------------|------------------|-------------------|-----------------------|-----|------|
| Deselected Cycle, Power Down | None | H | X | X | X | L | X | X | X | X | X | ↑ | HI-Z |
| Deselected Cycle, Power Down | None | L | X | H | L | X | X | X | X | X | X | ↑ | HI-Z |
| Deselected Cycle, Power Down | None | L | L | X | L | X | X | X | X | X | X | ↑ | HI-Z |
| Deselected Cycle, Power Down | None | L | X | H | X | L | X | X | X | X | X | ↑ | HI-Z |
| Deselected Cycle, Power Down | None | L | L | X | X | L | X | X | X | X | X | ↑ | HI-Z |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | H | ↑ | HI-Z |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | H | X | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | H | ↑ | HI-Z |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | L | X | ↑ | DIN |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | L | X | X | X | ↑ | DIN |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | H | ↑ | HI-Z |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | H | ↑ | HI-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | H | ↑ | HI-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | H | ↑ | HI-Z |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | H | L | L | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | L | X | X | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | H | L | L | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | L | X | X | X | ↑ | DIN |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | H | ↑ | HI-Z |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | H | ↑ | HI-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | H | ↑ | HI-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | H | ↑ | HI-Z |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | L | L | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | L | X | X | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | L | L | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | H | X | X | X | H | H | L | X | X | X | ↑ | DIN |

NOTES:

1. L = V_{IL}, H = V_{IH}, X = Don't Care.
2. \overline{OE} is an asynchronous input.
3. ZZ - low for the table.

5291 tbl 10

Synchronous Write Function Truth Table (1, 2)

| Operation | \overline{GW} | \overline{BWE} | \overline{BW}_1 | \overline{BW}_2 | \overline{BW}_3 | \overline{BW}_4 |
|-----------------------------|-----------------|------------------|-------------------|-------------------|-------------------|-------------------|
| Read | H | H | X | X | X | X |
| Read | H | L | H | H | H | H |
| Write all Bytes | L | X | X | X | X | X |
| Write all Bytes | H | L | L | L | L | L |
| Write Byte 1 ⁽³⁾ | H | L | L | H | H | H |
| Write Byte 2 ⁽³⁾ | H | L | H | L | H | H |
| Write Byte 3 ⁽³⁾ | H | L | H | H | L | H |
| Write Byte 4 ⁽³⁾ | H | L | H | H | H | L |

5291 tbl 11

NOTES:

1. L = V_{IL} , H = V_{IH} , X = Don't Care.
2. \overline{BW}_3 and \overline{BW}_4 are not applicable for the IDT71T67902.
3. Multiple bytes may be selected during the same cycle.

Asynchronous Truth Table (1)

| Operation ⁽²⁾ | \overline{OE} | ZZ | I/O Status | Power |
|--------------------------|-----------------|----|------------------|---------|
| Read | L | L | Data Out | Active |
| Read | H | L | High-Z | Active |
| Write | X | L | High-Z - Data In | Active |
| Deselected | X | L | High-Z | Standby |
| Sleep Mode | X | H | High-Z | Sleep |

5291 tbl 12

NOTES:

1. L = V_{IL} , H = V_{IH} , X = Don't Care.
2. Synchronous function pins must be biased appropriately to satisfy operation requirements.

Interleaved Burst Sequence Table ($\overline{LBO}=V_{DD}$)

| | Sequence 1 | | Sequence 2 | | Sequence 3 | | Sequence 4 | |
|-------------------------------|------------|----|------------|----|------------|----|------------|----|
| | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ⁽¹⁾ | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 |

5291 tbl 13

NOTE:

1. Upon completion of the Burst sequence the counter wraps around to its initial state.

Linear Burst Sequence Table ($\overline{LBO}=V_{SS}$)

| | Sequence 1 | | Sequence 2 | | Sequence 3 | | Sequence 4 | |
|-------------------------------|------------|----|------------|----|------------|----|------------|----|
| | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ⁽¹⁾ | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 |

5291 tbl 14

NOTE:

1. Upon completion of the Burst sequence the counter wraps around to its initial state.

AC Electrical Characteristics (V_{DD} = 2.5V ±5%, T_A = 0 to 70°C)

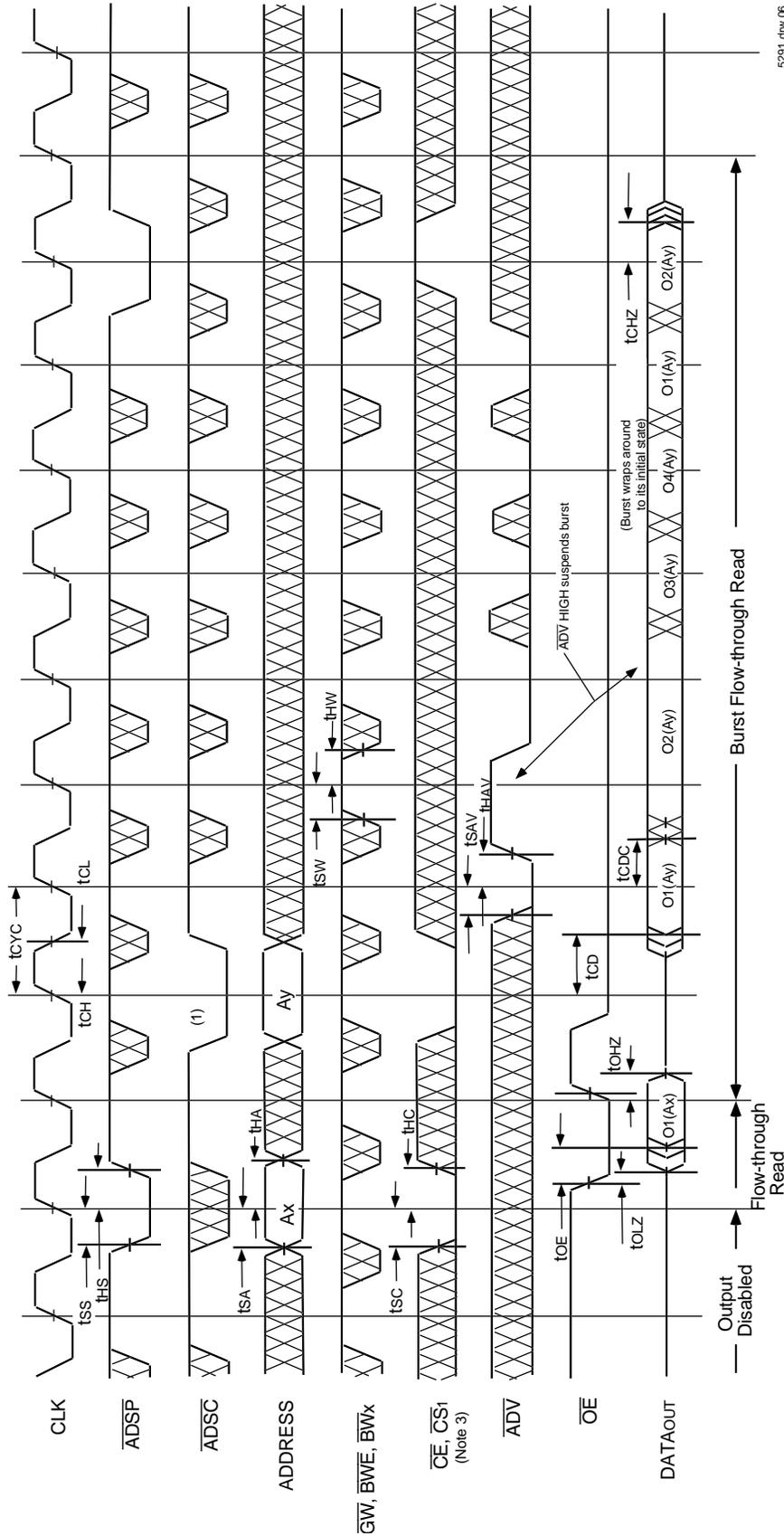
| Symbol | Parameter | 7.5ns | | 8ns | | 8.5ns | | Unit |
|--|-------------------------------------|-------|------|------|------|-------|------|------|
| | | Min. | Max. | Min. | Max. | Min. | Max. | |
| Clock Parameter | | | | | | | | |
| t _{CYC} | Clock Cycle Time | 8.5 | — | 10 | — | 11.5 | — | ns |
| t _{CH} ⁽¹⁾ | Clock High Pulse Width | 3 | — | 4 | — | 4.5 | — | ns |
| t _{CL} ⁽¹⁾ | Clock Low Pulse Width | 3 | — | 4 | — | 4.5 | — | ns |
| Output Parameters | | | | | | | | |
| t _{CD} | Clock High to Valid Data | — | 7.5 | — | 8 | — | 8.5 | ns |
| t _{DC} | Clock High to Data Change | 2 | — | 2 | — | 2 | — | ns |
| t _{CLZ} ⁽²⁾ | Clock High to Output Active | 0 | — | 0 | — | 0 | — | ns |
| t _{CHZ} ⁽²⁾ | Clock High to Data High-Z | 2 | 3.5 | 2 | 3.5 | 2 | 3.5 | ns |
| t _{OE} | Output Enable Access Time | — | 3.5 | — | 3.5 | — | 3.5 | ns |
| t _{OLZ} ⁽²⁾ | Output Enable Low to Output Active | 0 | — | 0 | — | 0 | — | ns |
| t _{OHZ} ⁽²⁾ | Output Enable High to Output High-Z | — | 3.5 | — | 3.5 | — | 3.5 | ns |
| Set Up Times | | | | | | | | |
| t _{SA} | Address Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| t _{SS} | Address Status Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| t _{SD} | Data In Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| t _{SW} | Write Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| t _{SAV} | Address Advance Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| t _{SC} | Chip Enable/Select Setup Time | 1.5 | — | 2 | — | 2 | — | ns |
| Hold Times | | | | | | | | |
| t _{HA} | Address Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| t _{HS} | Address Status Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| t _{HD} | Data In Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| t _{HW} | Write Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| t _{HAV} | Address Advance Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| t _{HC} | Chip Enable/Select Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| Sleep Mode and Configuration Parameters | | | | | | | | |
| t _{ZZPW} | ZZ Pulse Width | 100 | — | 100 | — | 100 | — | ns |
| t _{ZZR} ⁽³⁾ | ZZ Recovery Time | 100 | — | 100 | — | 100 | — | ns |
| t _{CFG} ⁽⁴⁾ | Configuration Set-up Time | 34 | — | 40 | — | 50 | — | ns |

5291 tbl 15

NOTES:

1. Measured as HIGH above V_{IH} and LOW below V_{IL}.
2. Transition is measured ±200mV from steady-state.
3. Device must be deselected when powered-up from sleep mode.
4. t_{CFG} is the minimum time required to configure the device based on the $\overline{\text{LBO}}$ input. $\overline{\text{LBO}}$ is a static input and must not change during normal operation.

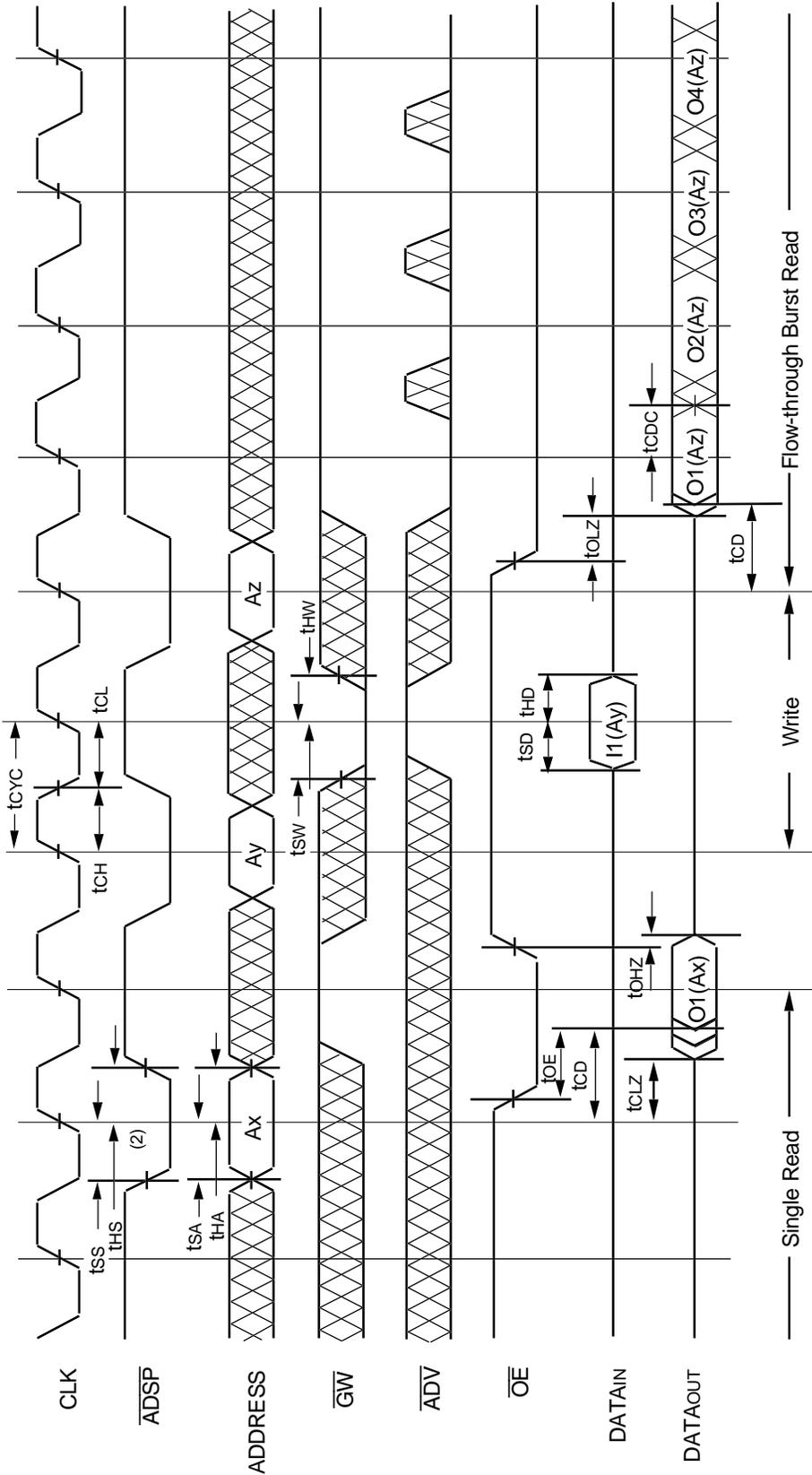
Timing Waveform of Flow-Through Read Cycle^(1,2)



NOTES:

1. O1 (Ax) represents the first output from the external address Ax. O1 (Ay) represents the first output from the external address Ay. O2 (Ay) represents the next output data in the burst sequence of the base address Ay, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the LBO input.
2. ZZ input is LOW and LBO is Don't Care for this cycle.
3. CS0 limiting transitions are identical but inverted to the \overline{CE} and $\overline{CS1}$ are LOW on this waveform, CS0 is HIGH.

Timing Waveform of Combined Flow-Through Read and Write Cycles^(1,2,3)

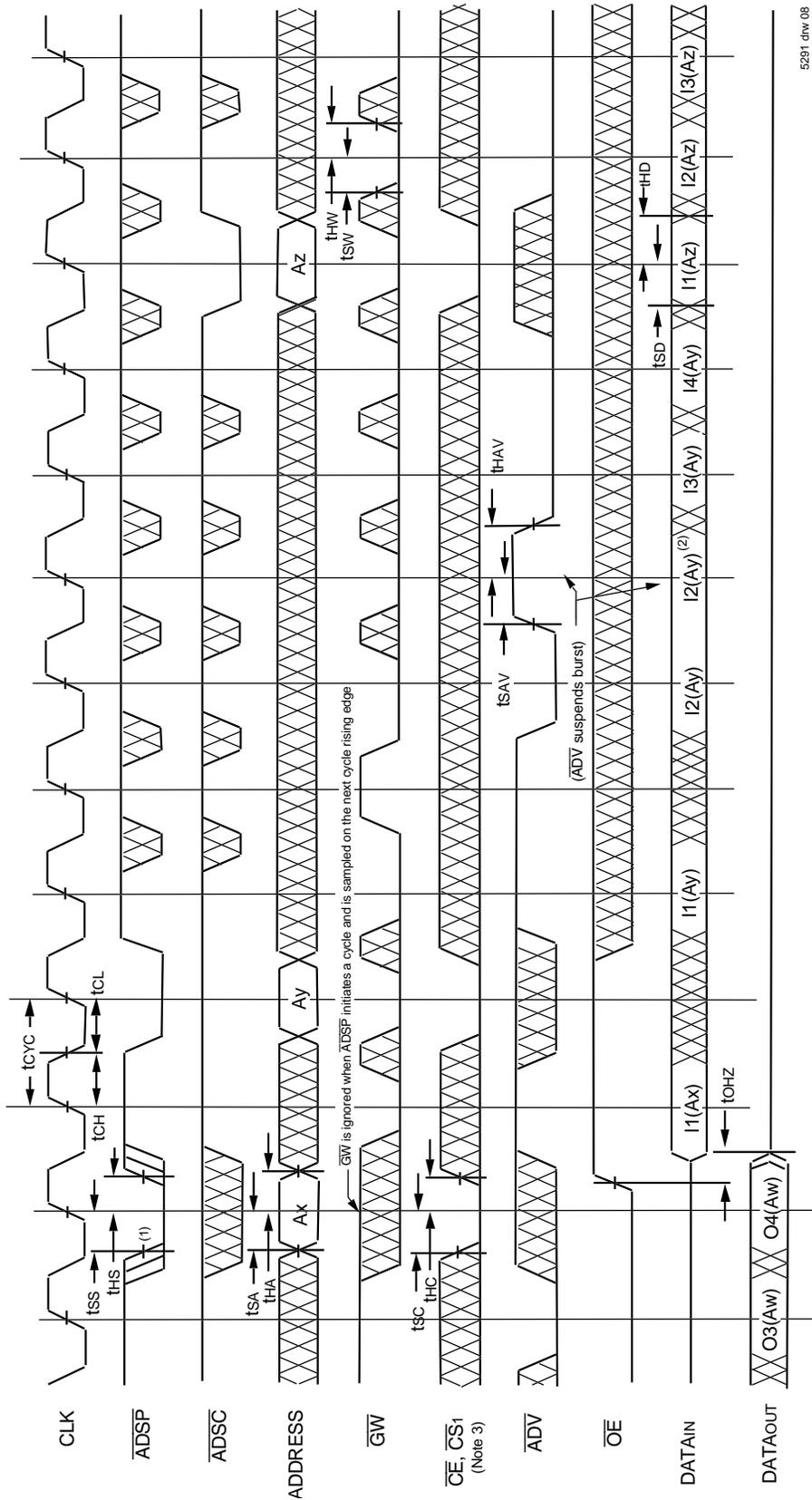


5291 dtw 07

NOTES:

1. Device is selected through entire cycle: \overline{OE} and $\overline{CS1}$ are LOW, $\overline{CS0}$ is HIGH.
2. ZZ input is LOW and LBO is Don't Care for this cycle.
3. O1 (Ax) represents the first output from the external address Ax. I1 (Ay) represents the first input from the external address Ay. O1 (Az) represents the first output from the external address Az. O2 (Az) represents the next output data in the burst sequence of the base address Az, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the LBO input.

Timing Waveform of Write Cycle No. 1 — \overline{GW} Controlled^(1,2,3)

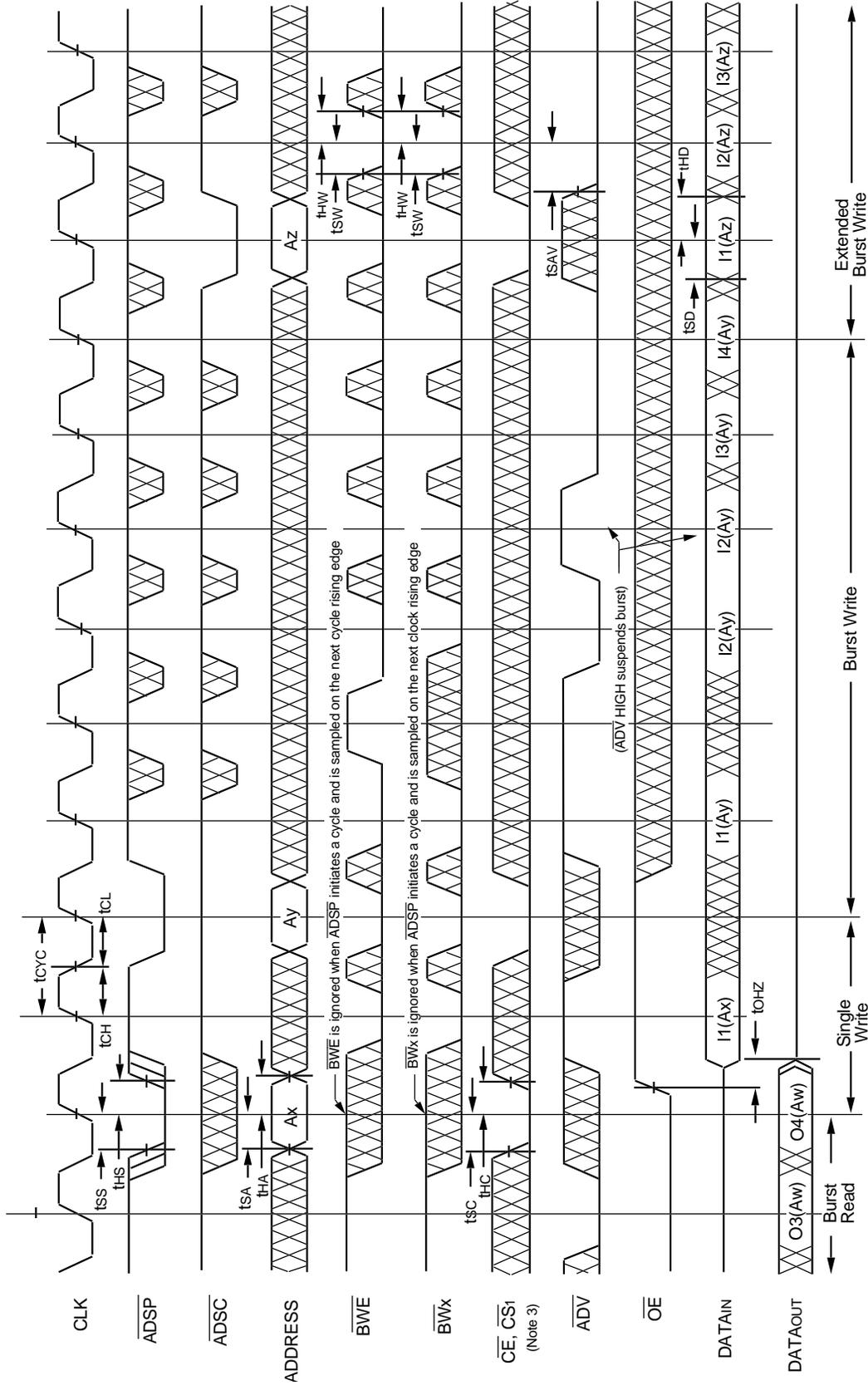


5291 drw 08

NOTES:

1. Z0 input is LOW, \overline{BWE} is HIGH and \overline{LBO} is Don't Care for this cycle.
2. 04 (Aw) represents the final output data in the burst sequence of the base address Aw. 11 (Ax) represents the first input from the external address Ax. 12 (Ay) represents the next input data in the burst sequence of the base address Ay, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the \overline{LBO} input. In the case of input 12 (Ay) this data is valid for two cycles because \overline{ADV} is high and has suspended the burst.
3. CS0 timing transitions are identical but inverted to the CE and CS1 signals. For example, when CE and CS1 are LOW on this waveform, CS0 is HIGH.

Timing Waveform of Write Cycle No. 2 — Byte Controlled^(1,2,3)

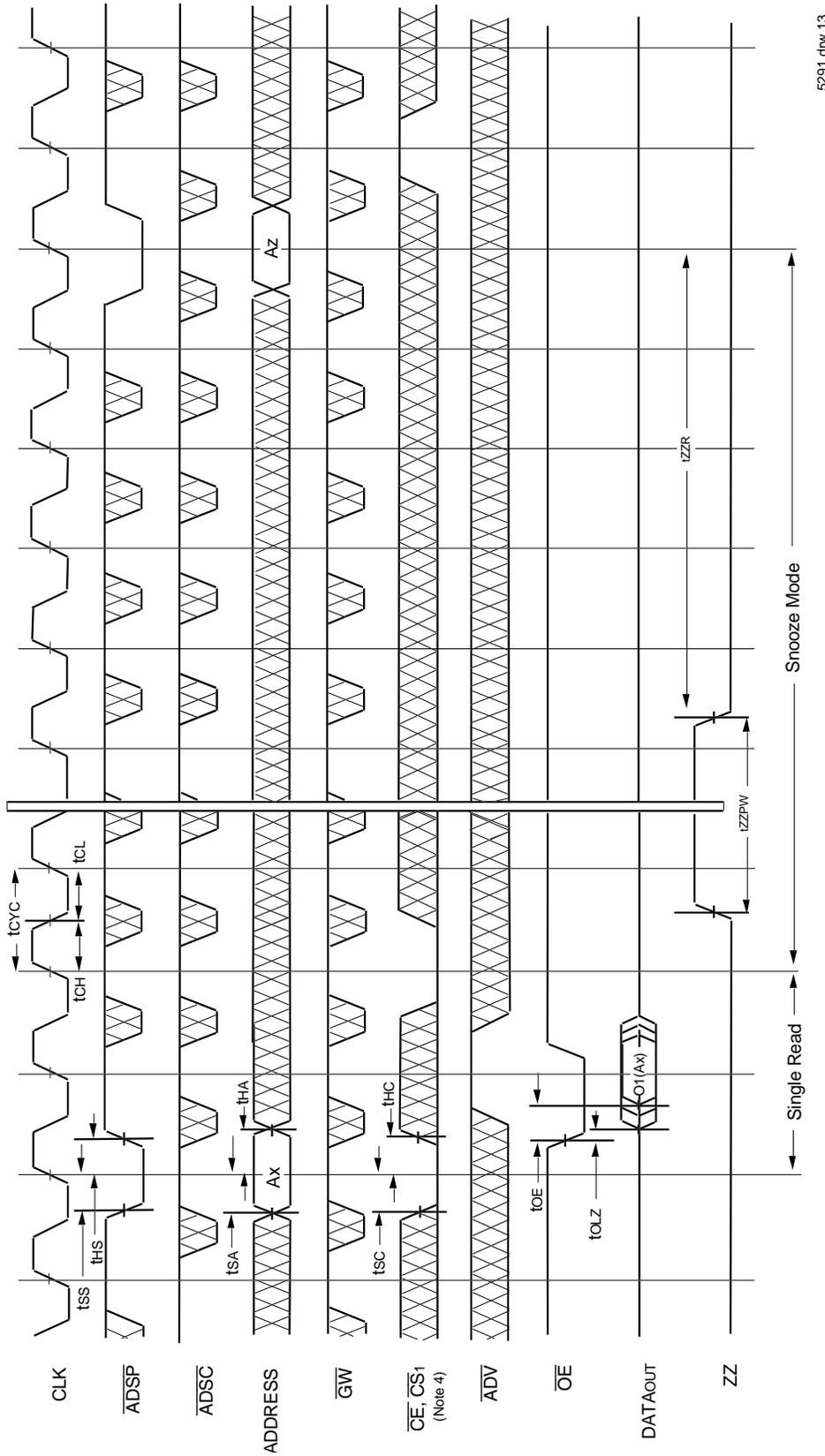


5291.drw 09

NOTES:

1. Zz input is LOW, $\overline{G\overline{W}}$ is HIGH and $\overline{LB\overline{O}}$ is Don't Care for this cycle.
2. O4 (Aw) represents the final output data in the burst sequence of the base address Aw. I1 (Ax) represents the first input from the external address Ax. I1 (Ay) represents the first input from the external address Ay. I2 (Ay) represents the next input data in the burst sequence of the base address Ay, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the $\overline{LB\overline{O}}$ input. In the case of input I2 (Ay) this data is valid for two cycles because ADV is high and has suspended the burst.
3. CS0 timing transitions are identical but inverted to the \overline{CE} and $\overline{CS1}$ signals. For example, when \overline{CE} and $\overline{CS1}$ are LOW on this waveform, CS0 is HIGH.

Timing Waveform of Sleep (ZZ) and Power-Down Modes^(1,2,3)

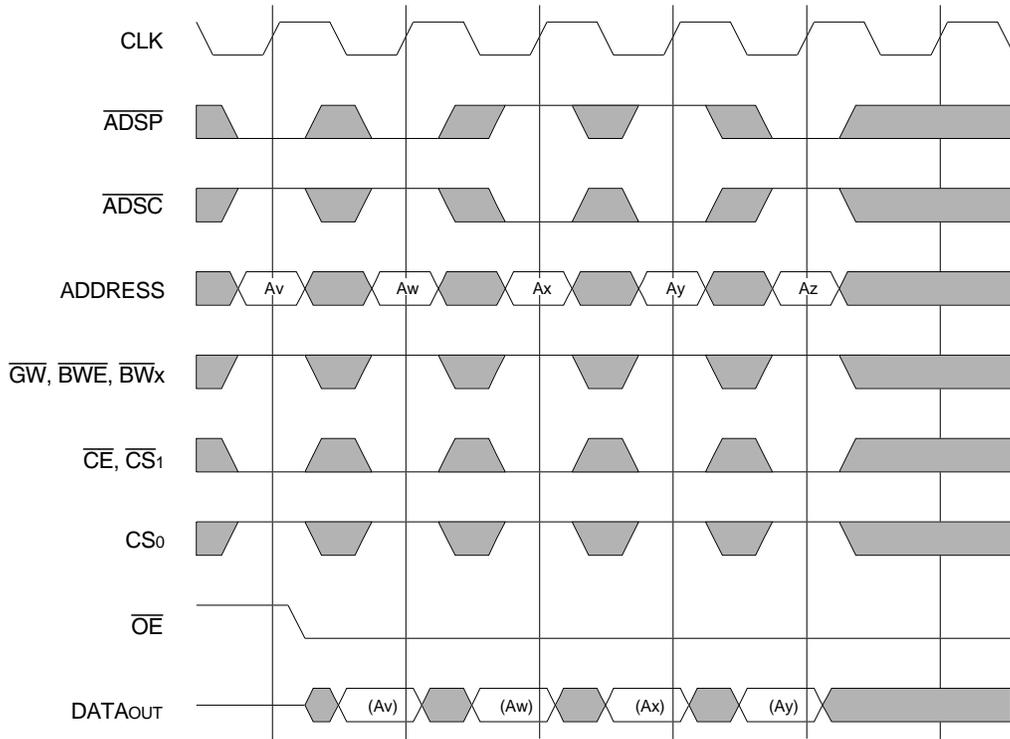


5291 drw 13

NOTES:

1. Device must power up in deselected Mode.
2. LBO is Don't Care for this cycle.
3. It is not necessary to retain the state of the input registers throughout the Power-down cycle.
4. CS0 timing transitions are identical but inverted to the CE and CS1 signals. For example, when CE and CS1 are LOW on this waveform, CS0 is HIGH.

Non-Burst Read Cycle Timing Waveform

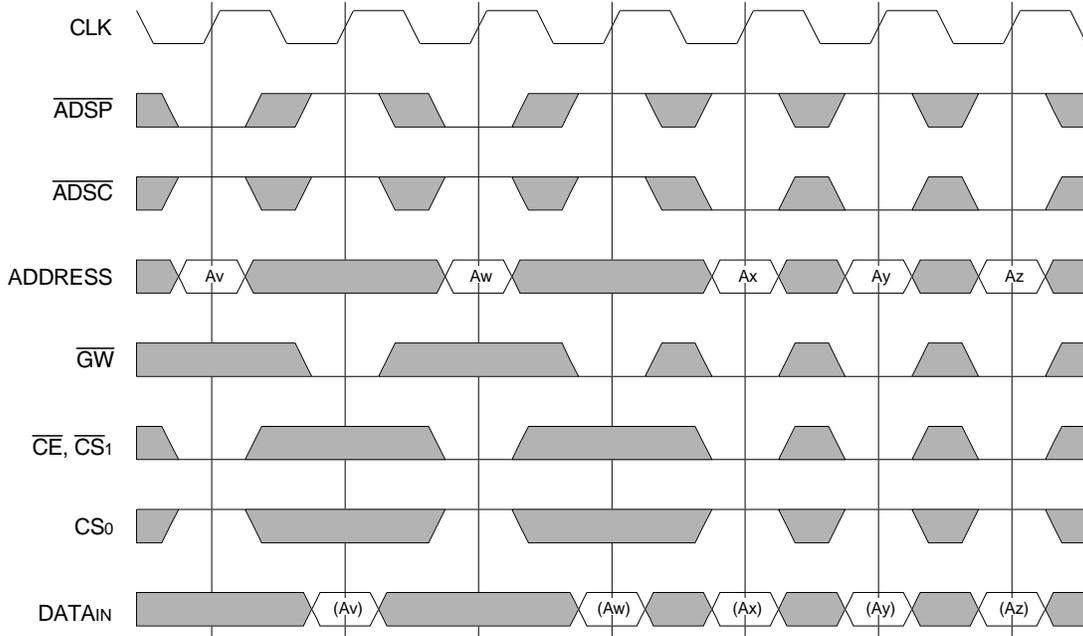


NOTES:

1. ZZ input is LOW, \overline{ADV} is HIGH and \overline{LBO} is Don't Care for this cycle.
2. (Ax) represents the data for address Ax, etc.
3. For read cycles, \overline{ADSP} and \overline{ADSC} function identically and are therefore interchangeable.

5291 drw 10

Non-Burst Write Cycle Timing Waveform

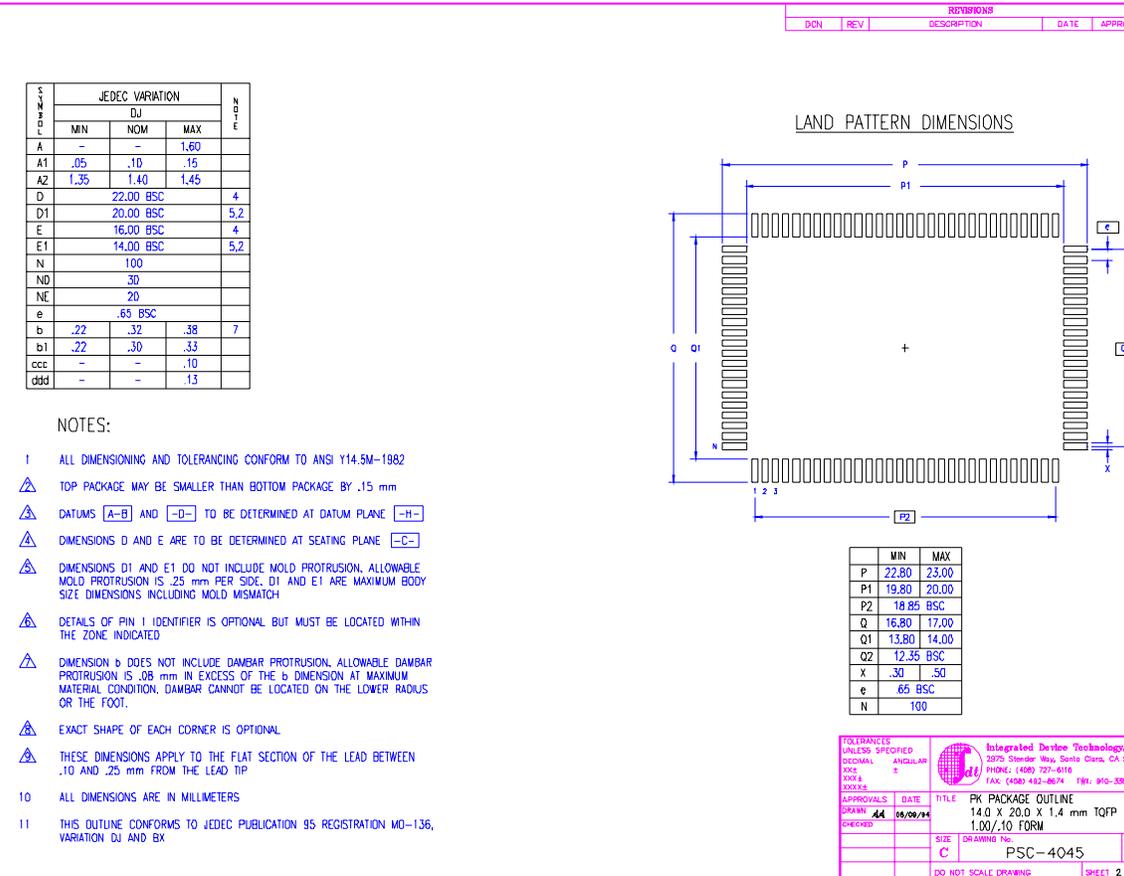
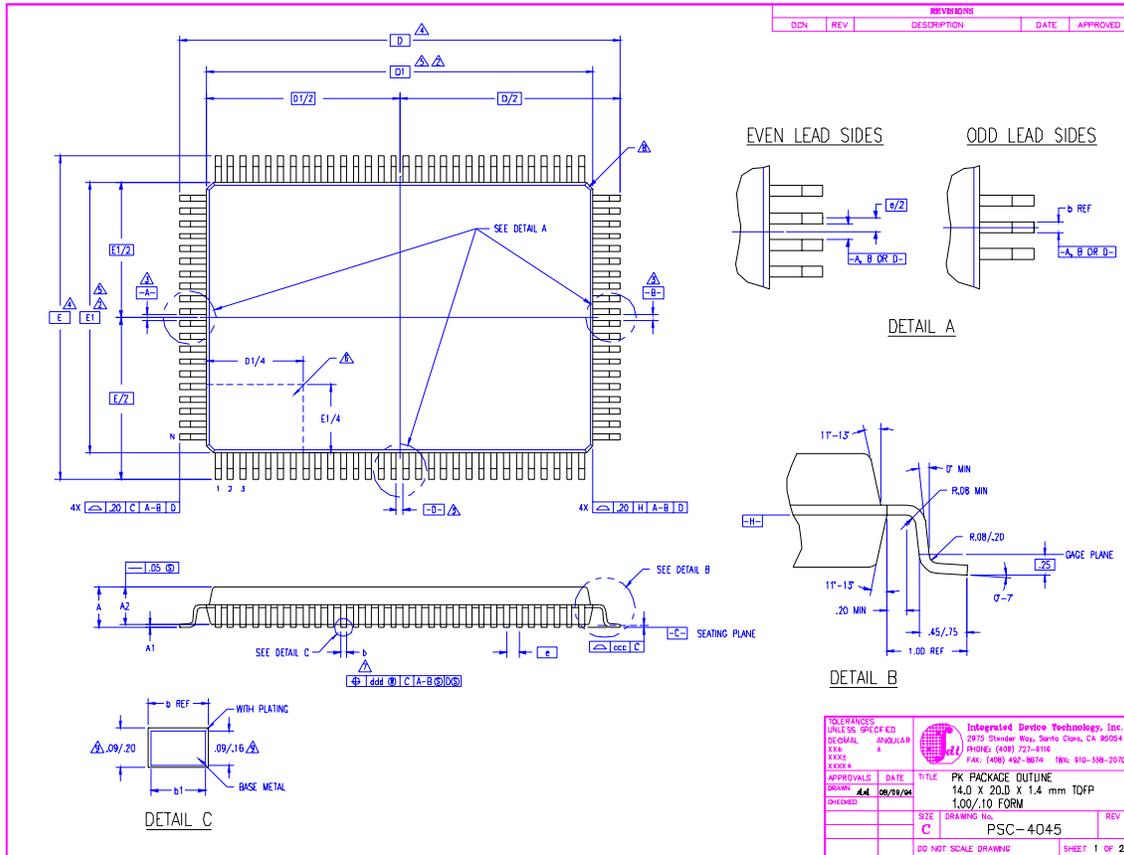


NOTES:

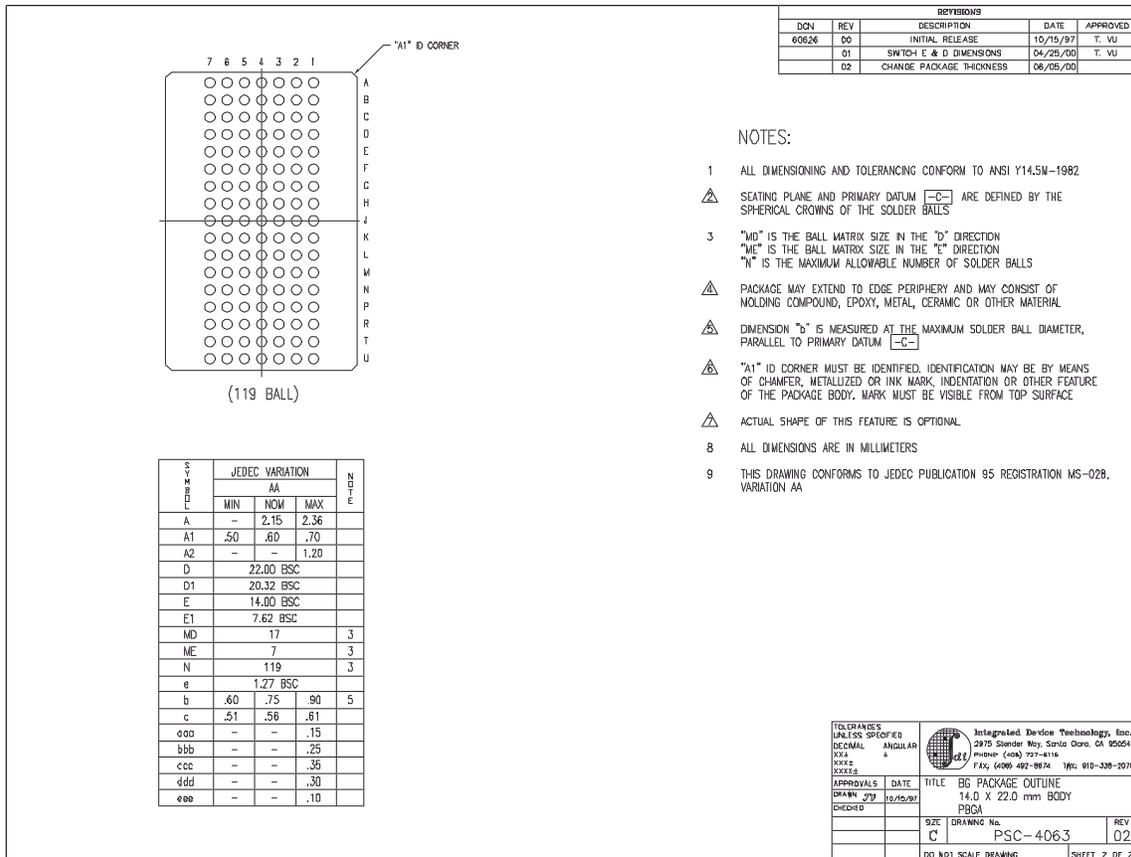
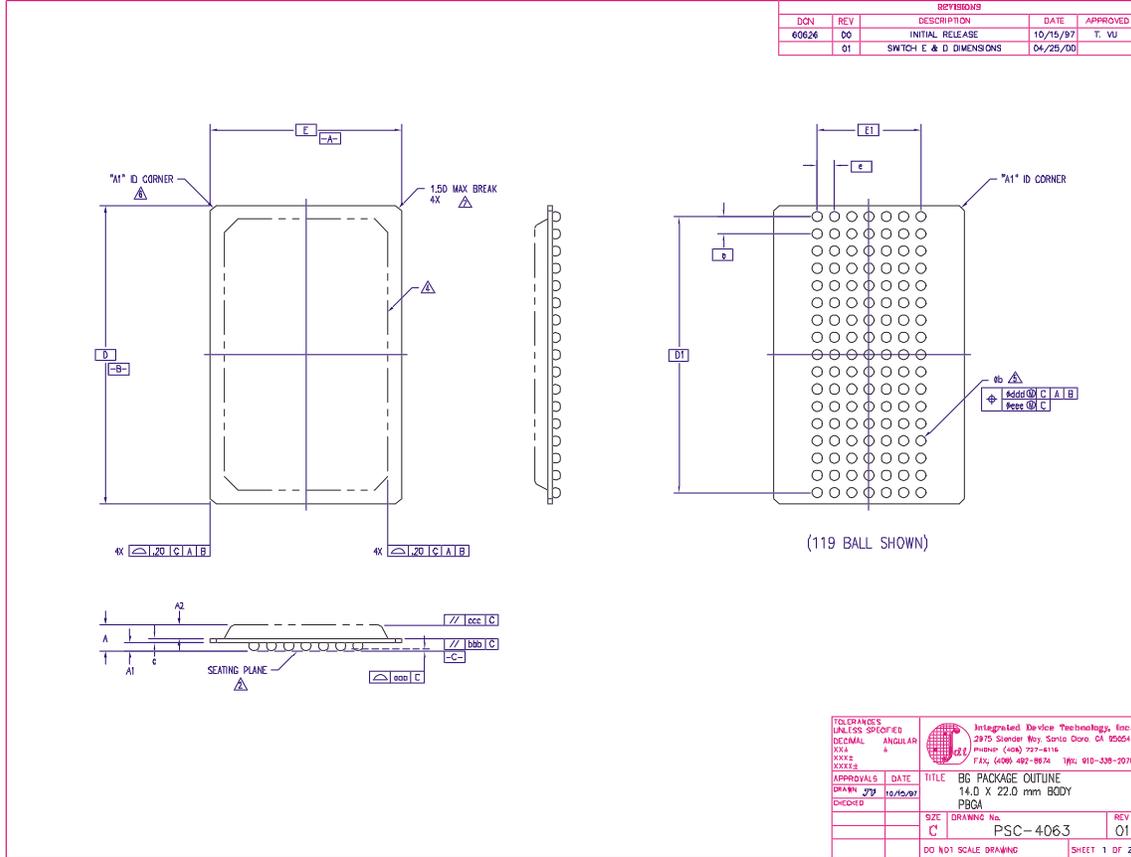
1. ZZ input is LOW, \overline{ADV} and \overline{OE} are HIGH, and \overline{LBO} is Don't Care for this cycle.
2. (Ax) represents the data for address Ax, etc.
3. Although only \overline{GW} writes are shown, the functionality of \overline{BWE} and \overline{BWx} together is the same as \overline{GW} .
4. For write cycles, \overline{ADSP} and \overline{ADSC} have different limitations.

5291 drw 11

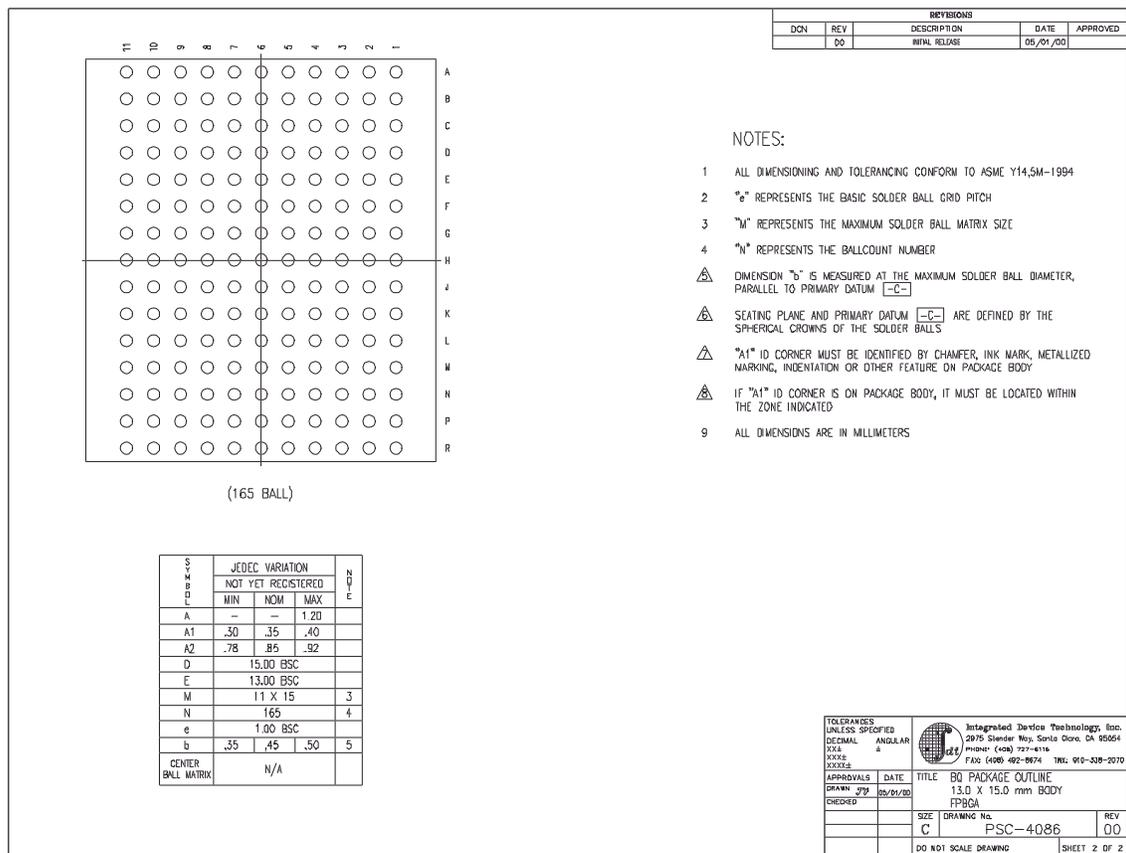
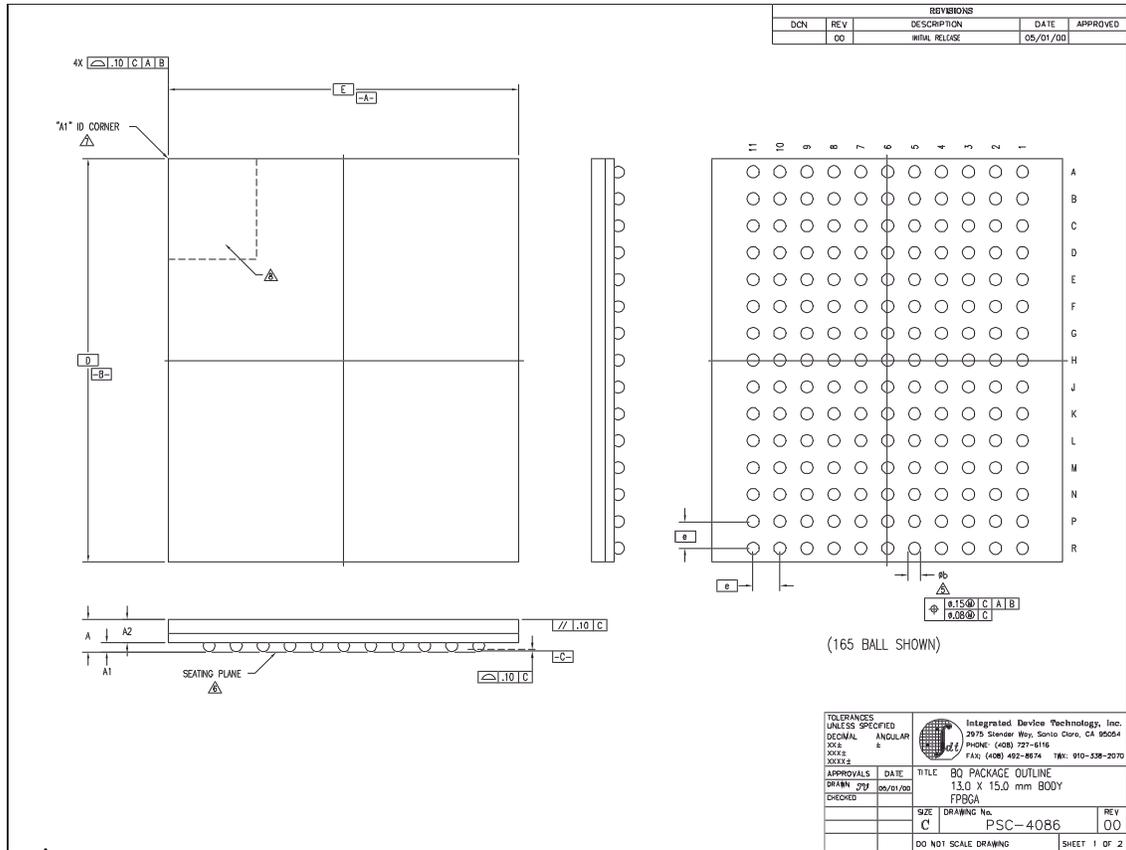
100-Pin Thin Quad Plastic Flatpack (TQFP) Package Diagram Outline



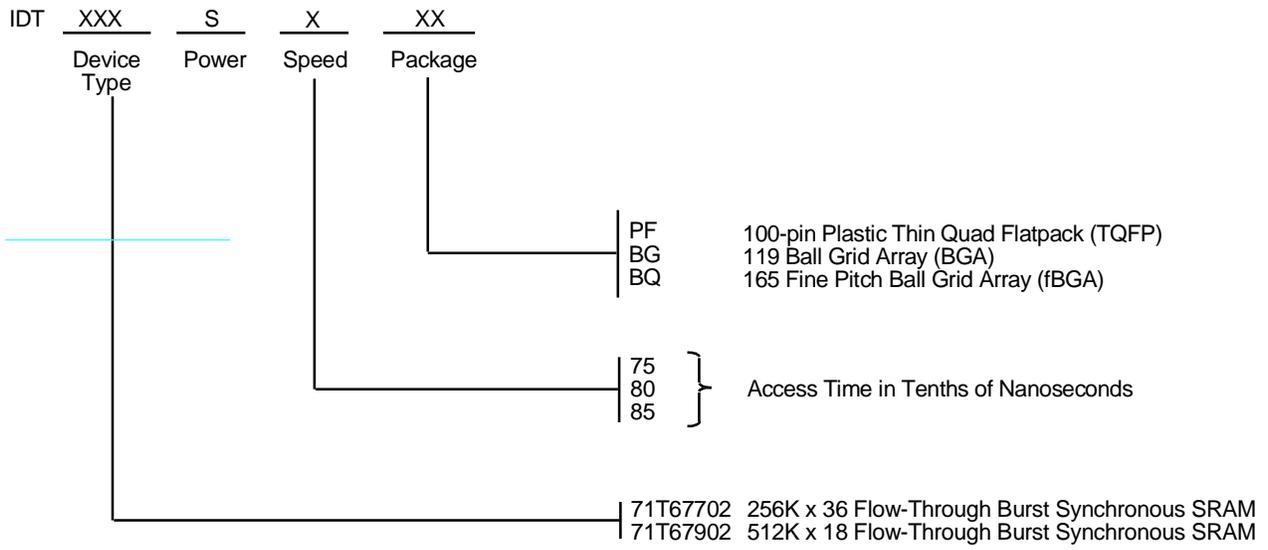
119 Ball Grid Array (BGA) Package Diagram Outline



165 Fine Pitch Ball Grid Array (fBGA) Package Diagram Outline



Ordering Information



5291 drw 12

Datasheet Document History

| | | |
|----------|-------------|--|
| 12/31/99 | | Created Datasheet |
| 06/10/00 | | Add new package offering, 13 x 15 fBGA |
| | Pg. 4 | Add capacitance for BGA package; Insert clarification note to Absolute Max Ratings and Recommended Operating Temperature tables. |
| | Pg. 5,6,7,8 | Correct note 2 on BGA and TQFP pin configuration |
| | Pg. 7 | Replace Pin U6 with $\overline{\text{TRST}}$ pin in BGA pin configuration; Add pin description note in pinout |
| | Pg. 18 | Inserted 100 pin TQFP Package Diagram Outline |
| | Pg. 20 | Correction in the 119 BGA Package Diagram Outline |
| 07/12/00 | Pg. 5,6,8 | Remove note from TQFP and BQ165 pinouts |
| | Pg. 7 | Add/Remove note from BG119 pinout |
| | Pg. 20 | Update BG119 package diagram outline dimensions |
| 07/16/01 | Pg. 9 | Updated ISB2 levels for tcd = 7.5ns - 8.5ns |



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
fax: 408-492-8674
www.idt.com

for Tech Support:
sramhelp@idt.com
800-544-7726, x4033

The IDT logo is a registered trademark of Integrated Device Technology, Inc.